



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT
SCHOTTKY BARRIER DIODE
VOLTAGE 30 Volts CURRENT 0.2 Ampere

CH481KGP

APPLICATION

- * Low power rectification

FEATURE

- * Small surface mounting type. (SC-82/SOT-343)
- * Extremely low forward voltage.
- * This is a composite component and is ideal for reducing the number of components used.
- * High reliability

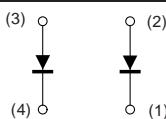
CONSTRUCTION

- * Silicon epitaxial planar

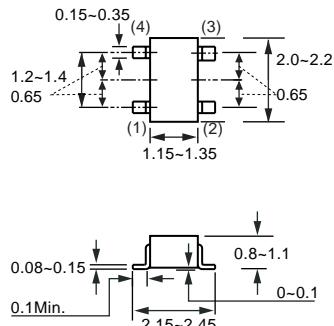
MARKING

- * 3R

CIRCUIT



SC-82/SOT-343



Dimensions in millimeters

SC-82/SOT-343

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CH481KGP	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	Volts
Maximum RMS Voltage	V _{RMS}	21	Volts
Maximum DC Blocking Voltage	V _D	30	Volts
Maximum Average Forward Rectified Current	I _o	0.2	Amps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	I _{FSM}	1.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	6.0	pF
Maximum Operating Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-40 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH481KGP	UNITS
Maximum Instantaneous Forward Voltage at I _{F(1)} = 10mA	V _{F(1)}	0.33	Volts
Maximum Instantaneous Forward Voltage at I _{F(2)} = 200mA	V _{F(2)}	0.50	Volts
Maximum Average Reverse Current at V _R = 10V	I _R	30	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 10.0 volts.
2. ESD sensitive product handling required.

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RATING CHARACTERISTIC CURVES (CH481KGP)

FIG. 1 FORWARD CHARACTERISTICS

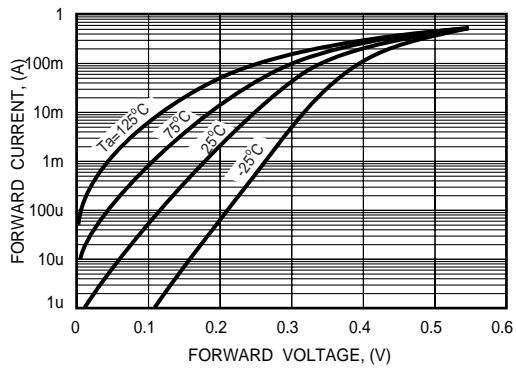


FIG. 2 - REVERSE CHARACTERISTICS

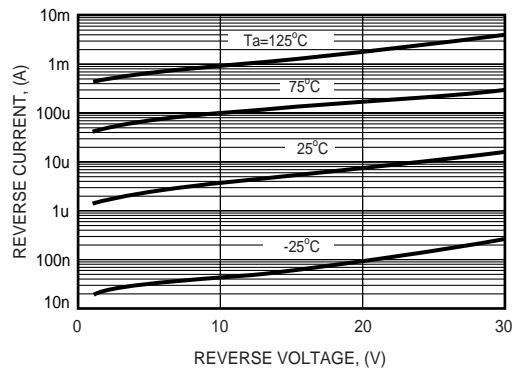


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

